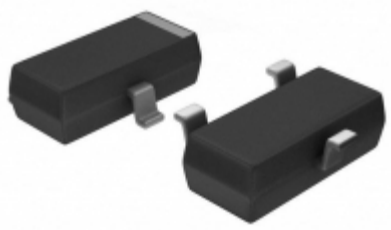
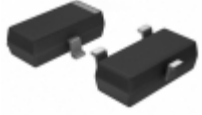


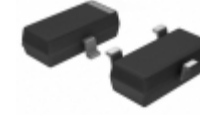




	<h2 style="color: red;">FJV3110RMTF</h2>
	<p>Hersteller-Teilenummer: FJV3110RMTF</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: TRANS PREBIAS NPN 200MW SOT23-3</p> <p>Datenblätter: 1.FJV3110RMTF.pdf 2.FJV3110RMTF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 30980 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FJV3110RMTF
Hersteller	Fairchild/ON Semiconductor
Beschreibung	TRANS PREBIAS NPN 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	30980 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	40V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 1mA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	100 @ 1mA, 5V
Frequenz - Übergang	250MHz
Widerstand - Base (R1) (Ohm)	10k
Widerstand - Emitter-Basis (R2) (Ohm)	-
Verpackung	Tape & Reel (TR)

FJV3110RMTF ist neu im Original, Suche FJV3110RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3110RMTF Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3110RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FJV3111RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3109RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3108RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3113RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>
 <p>FJV3112RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3112RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3111RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3109R FAIRCHI FJV3109R FAIRCHI</p>

heiße Teile

Mehr

⚙ FJV1845PMTF	➔ FJV1845PMTF	➔ FJV1845UMTF	D FJV1845UMTF	➔ FJV3101RLIMTF
⊣ FJV3101RMTF	⚙ FJV3101RMTF	D FJV3102RMTF	➔ FJV3102RMTF	➔ FJV3103RMTF
⚙ FJV3103RMTF	⊣ FJV3104RMTF	⚙ FJV3104RMTF	➔ FJV3105RMTF	➔ FJV3105RMTF
D FJV3106RMTF	⚙ FJV3106RMTF	⊣ FJV3107RMTF	⚙ FJV3107RMTF	➔ FJV3108RMTF
➔ FJV3108RMTF	➔ FJV3109R	⚙ FJV3109RMTF	⊣ FJV3109RMTF	➔ FJV3110RMTF
➔ FJV3111RMTF	➔ FJV3111RMTF	D FJV3112RMTF	⚙ FJV3112RMTF	⊣ FJV3113RMTF
⚙ FJV3113RMTF	D FJV3114RMTF	➔ FJV3114RMTF	➔ FJV3115RMTF	➔ FJV3115RMTF
⊣ FJV4101RMTF	⚙ FJV4101RMTF	➔ FJV4102RLIMTF	➔ FJV4102RMTF	➔ FJV4102RMTF
⚙ FJV4103RMTF	⊣ FJV4103RMTF	⚙ FJV4104RMTF	D FJV4104RMTF	➔ FJV4105RMTF
➔ FJV4105RMTF	⚙ FJV4106RMTF	⊣ FJV4106RMTF	⚙ FJV4107RMTF	➔ FJV4107RMTF

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